Triacs logic level

BT136F series D

GENERAL DESCRIPTION

Glass passivated, sensitive gate triacs in a full pack plastic envelope, intended for use in general purpose bidirectional switching and phase control applications. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

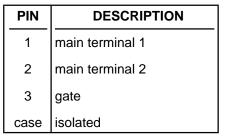
PINNING - SOT186

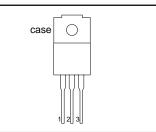
QUICK REFERENCE DATA

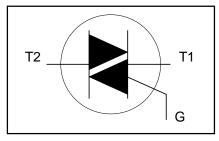
SYMBOL	PARAMETER	MAX.	MAX.	UNIT
V _{drm} I _{t(rms)} I _{tsm}	BT136F- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	500D 500 4 25	600D 600 4 25	V A A

PIN CONFIGURATION

SYMBOL







LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MA	AX.	UNIT
V _{drm}	Repetitive peak off-state voltages		-	-500 500 ¹	-600 600 ¹	V
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{hs} \le 92 \degree C$ full sine wave; $T_j = 125 \degree C$ prior to surge; with reapplied $V_{DRM(max)}$	-	2	4	A
		t = 20 ms	-		5	A
l ² t	I ² t for fusing	t = 16.7 ms t = 10 ms	-		.7 .1	A A ² s
dl _T /dt	Repetitive rate of rise of on-state current after	$I_{TM} = 6 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$		5	. 1	
	triggering	T2+ G+ T2+ G-	-		0 0	A/μs A/μs
		T2- G-	-		60	A/μs
		T2- G+	-	1	0	A/μs
I _{GM} V _{GM}	Peak gate current		-	4	2 5 5	Á
V _{GM}	Peak gate voltage Peak gate power		-		5	V W
$\begin{array}{c} P_{GM} \\ P_{G(AV)} \\ T_{stg} \\ T_{j} \end{array}$	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	- -40 -	0 1:	5 .5 50 25	ວໍດູ≪

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 3 $A/\mu s$.

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ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	Repetitive peak voltage from all three terminals to external heatsink	$R.H. \leq 65\%$; clean and dustfree	-		1500	V
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	12	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-hs} R _{th j-a}	Thermal resistance junction to heatsink Thermal resistance junction to ambient	full or half cycle with heatsink compound without heatsink compound in free air		- - 55	5.5 7.2 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$					
01			T2+ G+	-	2.0	5	mA
		-	T2+ G-	-	2.5	5	mA
		-	T2- G-	-	2.5	5	mA
			T2- G+	-	5.0	10	mA
I,	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$					
-			T2+ G+	-	1.6	10	mA
		-	T2+ G-	-	4.5	15	mA
		-	T2- G-	-	1.2	10	mA
		-	T2- G+	-	2.2	15	mA
I _H	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$		-	1.2	10	mA
I _H V⊤	On-state voltage	$I_{T} = 5 A$		-	1.4	1.70	V
V _{GT}	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$		-	0.7	1.5	V
		$V_{\rm D} = 400 \text{ V}; I_{\rm T} = 0.1 \text{ A}; T_{\rm i} = 125^{\circ}$	С	0.25	0.4	-	V
I _D	Off-state leakage current	$V_{D}^{i} = 400 \text{ V}; I_{T} = 0.1 \text{ A}; T_{j} = 125 \text{ °V}$ $V_{D} = V_{DRM(max)}; T_{j} = 125 \text{ °C}$		-	0.1	0.5	mA

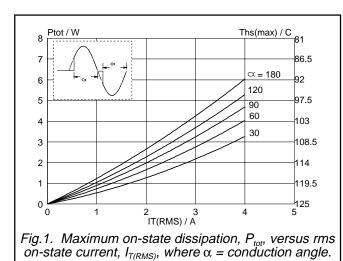
DYNAMIC CHARACTERISTICS

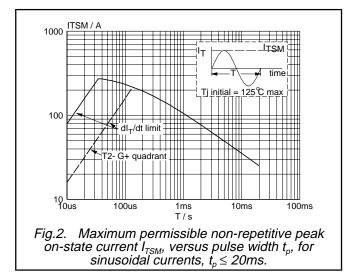
 $T_j = 25$ °C unless otherwise stated

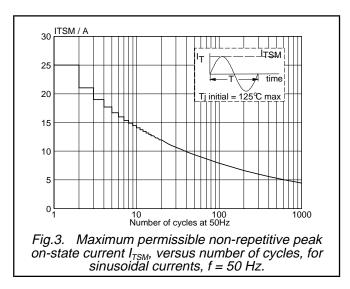
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; $R_{GK} = 1 k\Omega$	-	5	-	V/μs
t _{gt}		$I_{TM} = 6 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A}; $ $dI_G/dt = 5 \text{ A/}\mu\text{s}$	-	2	-	μs

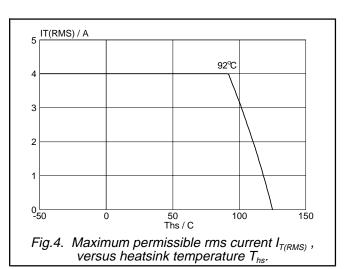
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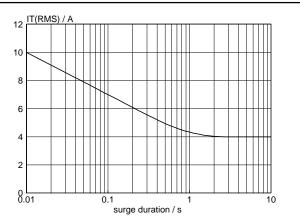
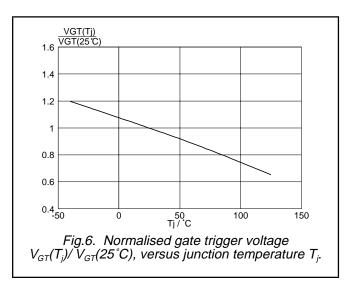
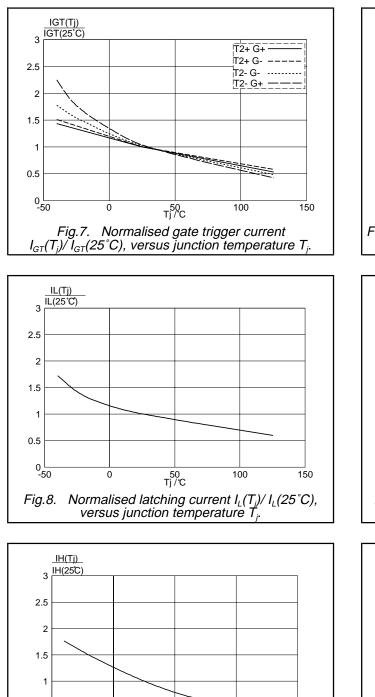


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{hs} \le 92^{\circ}C$.



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50 Tj /℃

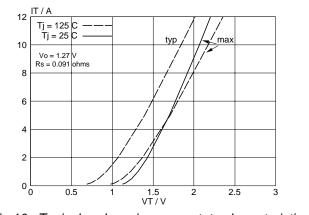
Fig.9. Normalised holding current $I_H(T_i)/I_H(25^{\circ}C)$,

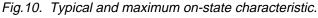
versus junction temperature T_i

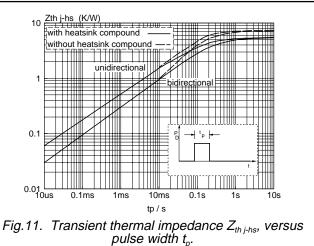
0

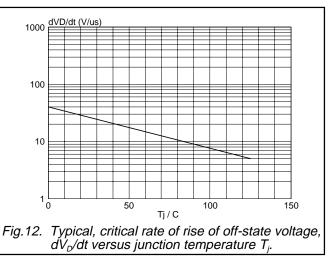
100

150









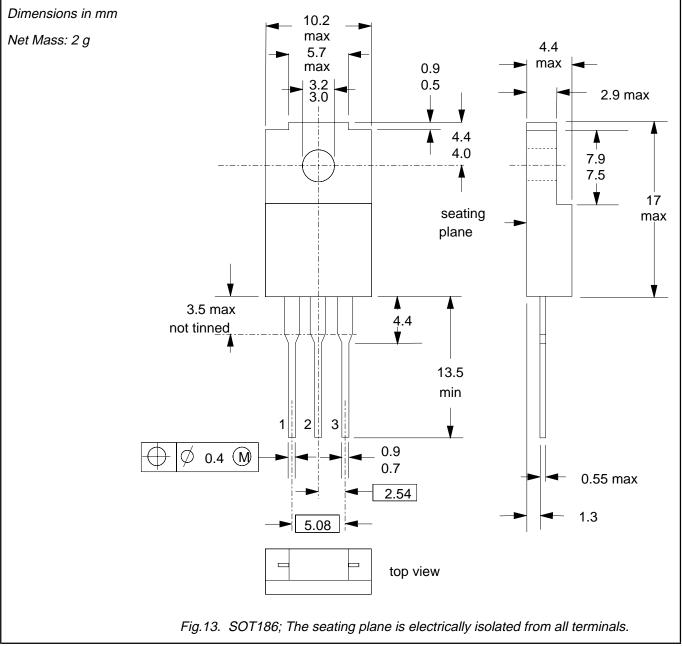
0.5

0∟ -50

Product specification

BT136F series D

MECHANICAL DATA



Notes

Accessories supplied on request: refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information				
Where application information is given, it is advisory and does not form part of the specification.				

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